UNISONIC TECHNOLOGIES CO., LTD

MGBR10V45C

Preliminary

DIODE

DUAL MOS GATED BARRIER RECTIFIER

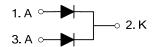
DESCRIPTION

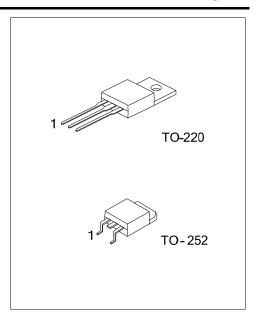
The UTC **MGBR10V45C** is a dual mos gated barrier rectifiers, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed, etc.

■ FEATURES

- * Very low forward voltage drop
- * High switching speed

■ SYMBOL

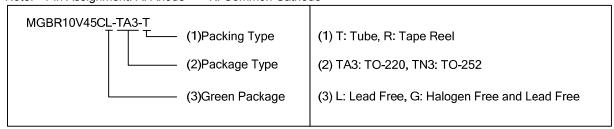




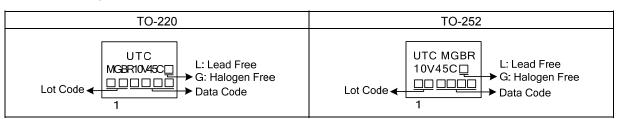
■ ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Deakins	
Lead Free	Halogen Free	Package	1	2	3	Packing	
MGBR10V45CL-TA3-T	MGBR10V45CG-TA3-T	TO-220	Α	K	Α	Tube	
MGBR10V45CL-TN3-R	MGBR10V45CG-TN3-R	TO-252	Α	K	Α	Tape Reel	

Note: Pin Assignment: A: Anode K: Common Cathode



MARKING



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■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C, unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER		SYMBOL	RATINGS	UNIT
DC Blocking Voltage		V_{RM}	45	V
Working Peak Reverse Voltage		V_{RWM}	45	V
Peak Repetitive Reverse Voltage		V_{RRM}	45	V
RMS Reverse Voltage		$V_{R(RMS)}$	32	V
Average Rectified Output Current	Per Leg		5	Α
(T _C =140°C)	Total	I _O	10	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM}	90	Α
Repetitive Peak Avalanche Power (1µs, 25°C)		P_{ARM}	5000	W
Operating Junction Temperature		T_J	-65~+150	°C
Storage Temperature		T_{STG}	-65~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL CHARACTERISTICS

PARAMETER		SYMBOL	RATINGS	UNIT	
Junction to Ambient	TO-220	0	62.5	°C/W	
	TO-252	9 _{JA}	110		
Junction to Case	TO-220	0	2	°C/W	
	TO-252	θ _{JC}	2.5		

■ ELECTRICAL CHARACTERISTICS (Per Leg) (T_A =25°C, unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.45mA	45			V
Forward Voltage Drop	V _{FM}	I _F =5A, T _J =25°C			0.50	V
		I _F =5A, T _J =125°C			0.45	V
Leakage Current (Note 1)	I I I I I I I I I I I I I I I I I I I	V _R =45V, T _J =25°C		50	500	μΑ
		V _R =45V, T _J =125°C		12	40	mA

Notes: 1. Short duration pulse test used to minimize self-heating effect.

^{2.} Thermal resistance junction to case mounted on heatsink.

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DIODE